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**Takehita et al.**

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(54) **SEMICONDUCTOR DEVICE AND METHOD FOR MANUFACTURING THE SAME**

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tion).

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filed on May 11, 2015, now abandoned, which is a  
division of application No. 14/320,366, filed on Jun.  
30, 2014, now Pat. No. 9,059,368, which is a division  
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(57) **ABSTRACT**

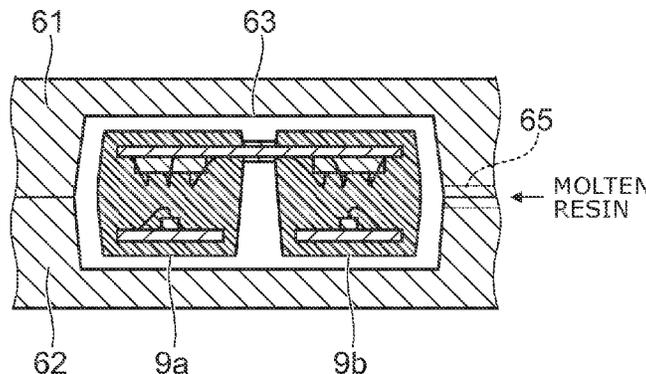
(51) **Int. Cl.**  
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**H01L 31/16** (2006.01)  
(Continued)

A semiconductor device includes first, second, and third  
molded bodies. The first molded body covers a first light  
emitting element, a part of a lead electrically connected to  
the first light emitting element, a first light receiving element  
configured to detect a light emitted from the first light  
emitting element, and a part of a lead electrically connected  
to the first light receiving element with a first resin. The  
second molded body covers a second light emitting element,  
a part of a lead electrically connected to the second light  
emitting element, a second light receiving element config-  
ured to detect a light emitted from the second light emitting  
element, and a part of a lead electrically connected to the  
second light receiving element with the first resin. The third  
molded body molds the first and the second molded bodies  
as one body using a second resin.

(52) **U.S. Cl.**  
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(58) **Field of Classification Search**  
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H01L 31/173; H01L 2224/48247; H01L  
2224/48257; H01L 25/167; H01L 31/02164;  
H01L 31/0232

**12 Claims, 7 Drawing Sheets**



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*H01L 31/0203* (2014.01)  
*H01L 31/12* (2006.01)  
*H01L 31/167* (2006.01)  
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- (52) **U.S. Cl.**  
CPC ..... *H01L31/0203* (2013.01); *H01L 31/02005*  
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*31/16* (2013.01); *H01L 31/167* (2013.01);  
*H01L 31/173* (2013.01); *H01L 2224/05554*  
(2013.01); *H01L 2224/45144* (2013.01); *H01L*  
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(2013.01); *H01L 2224/48257* (2013.01)

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FIG. 1A

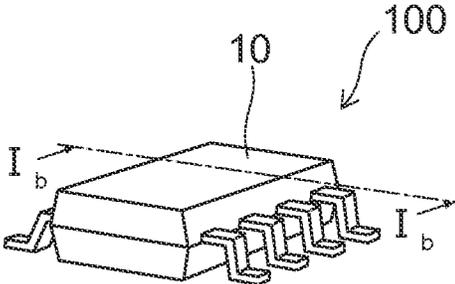


FIG. 1B

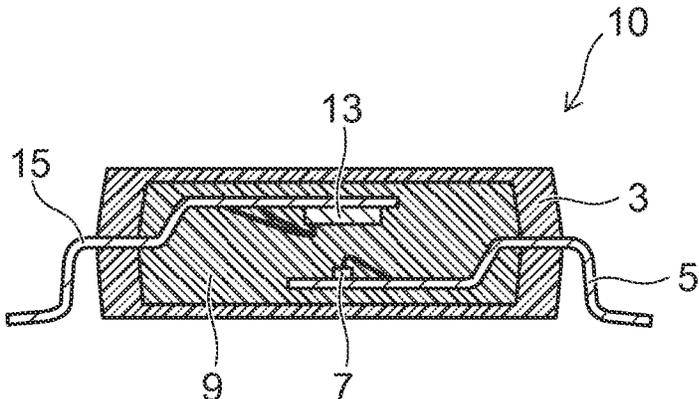


FIG. 2A

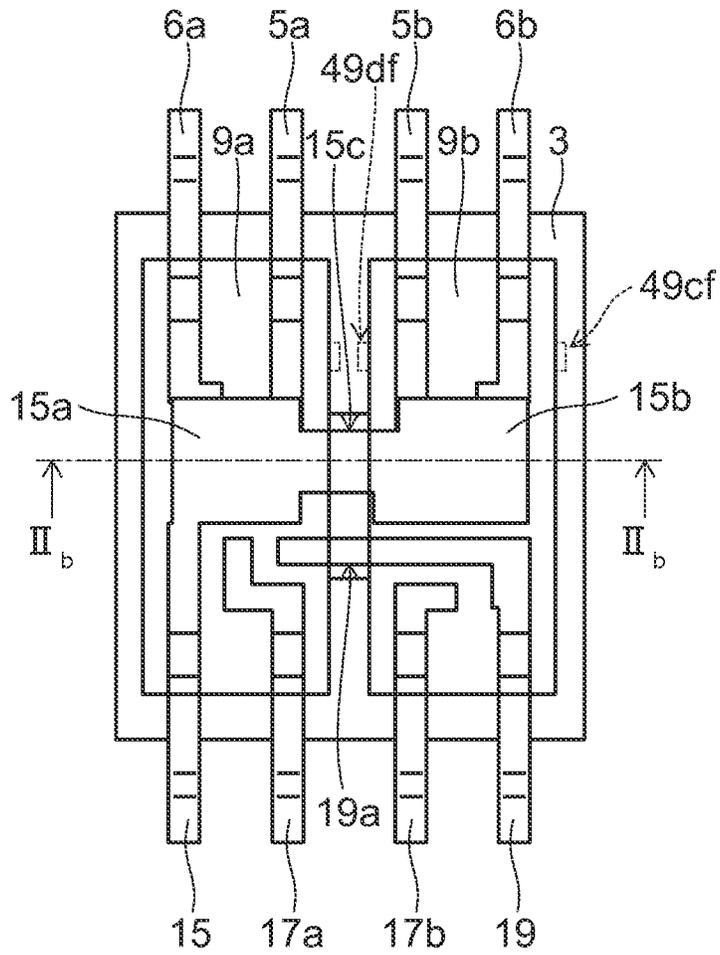
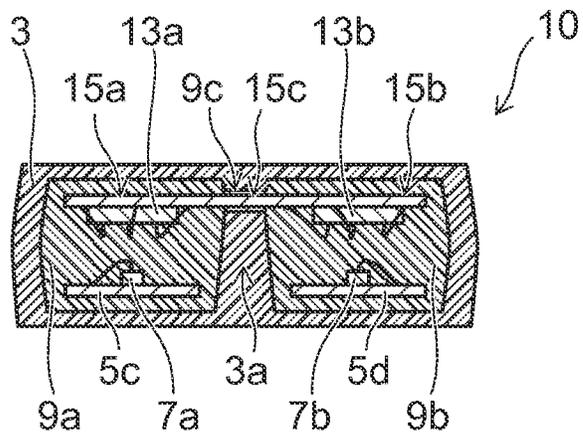


FIG. 2B



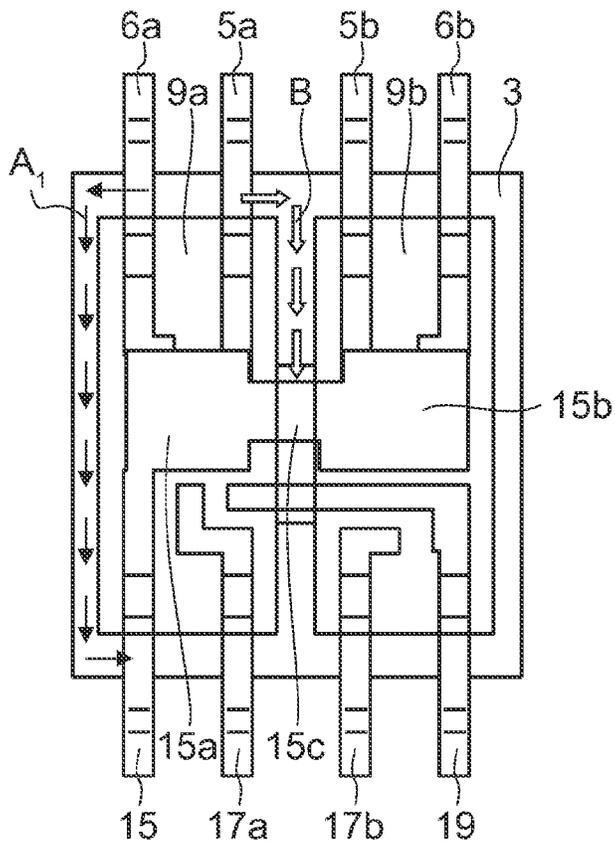


FIG. 3A

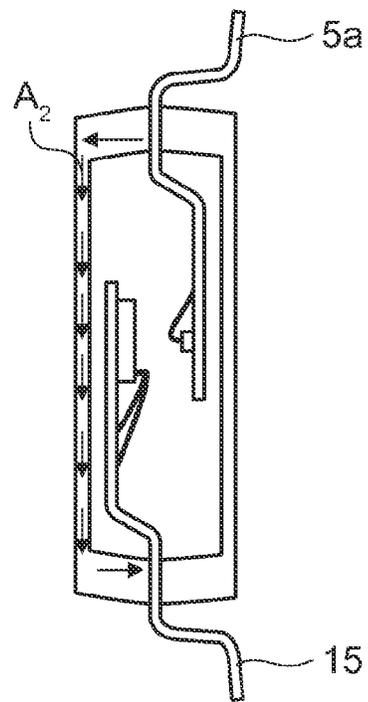


FIG. 3B

FIG. 4A

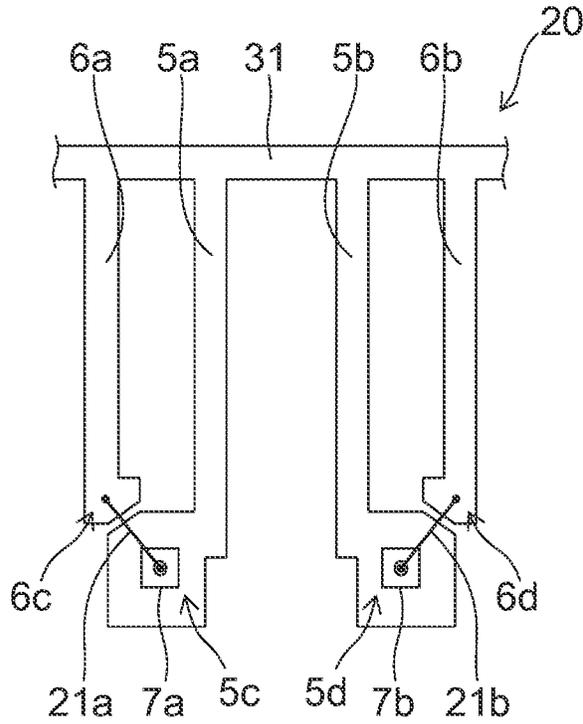
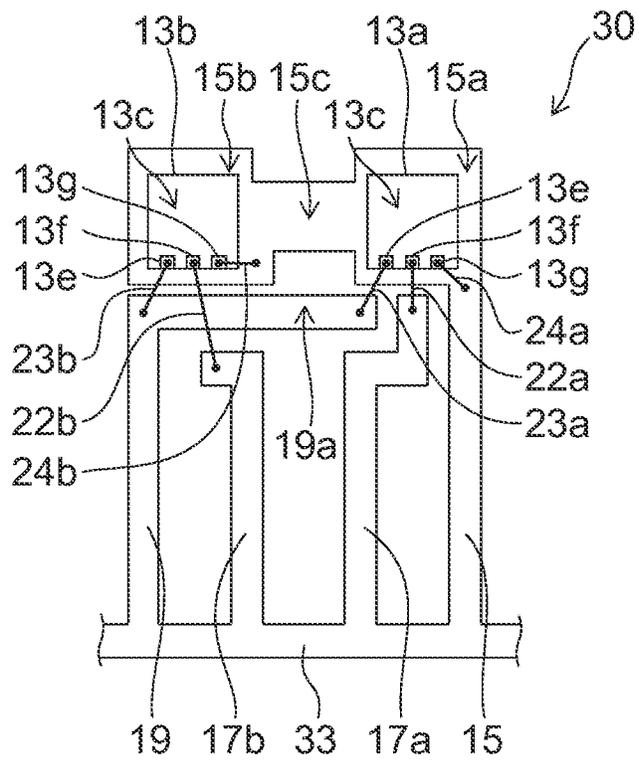


FIG. 4B



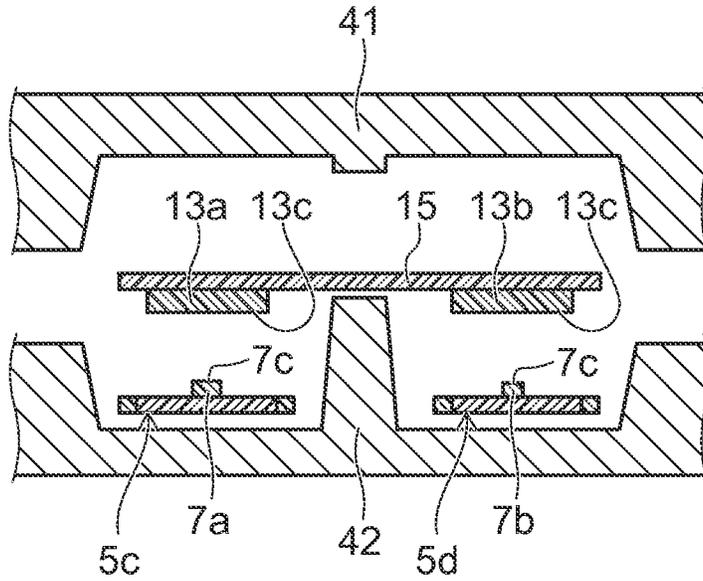


FIG. 5A

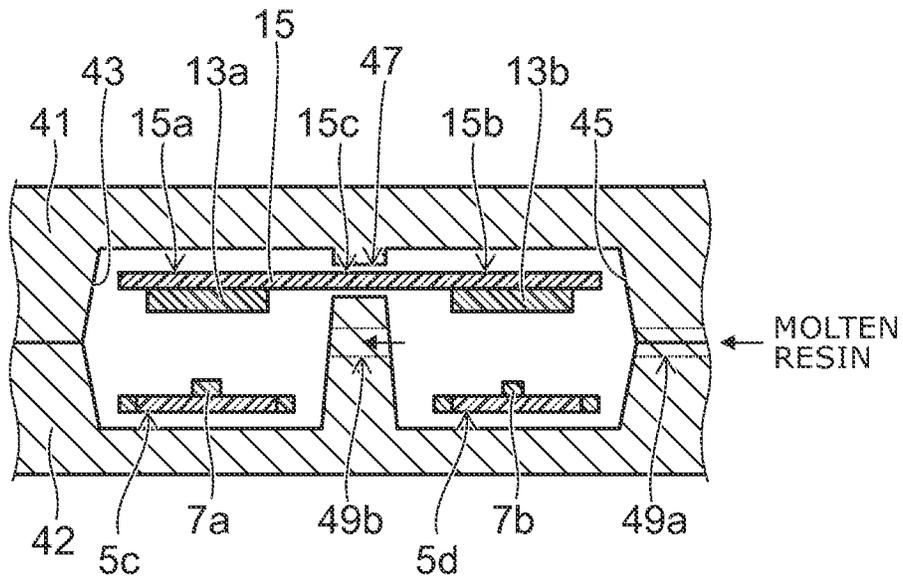


FIG. 5B

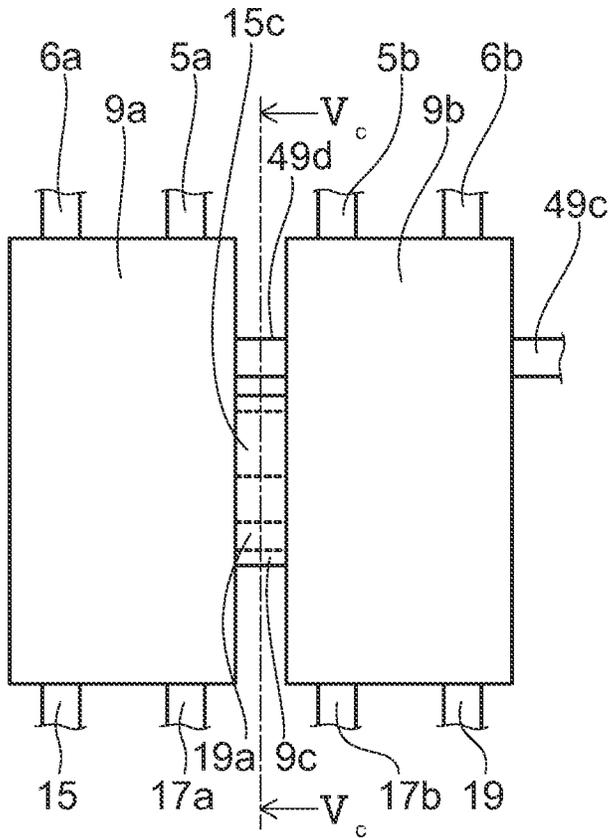


FIG. 6A

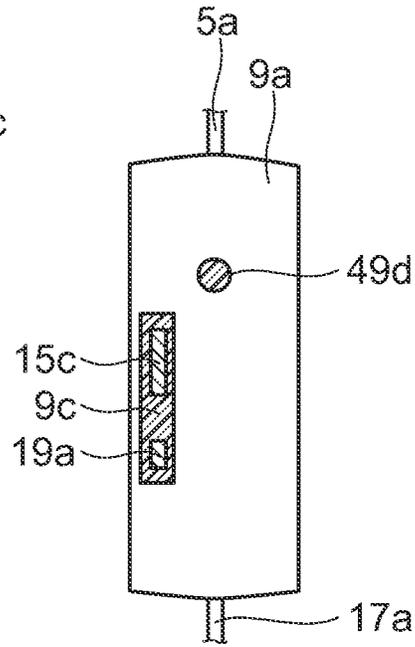


FIG. 6C

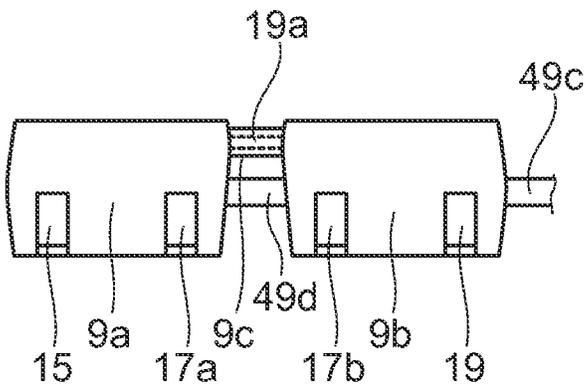


FIG. 6B

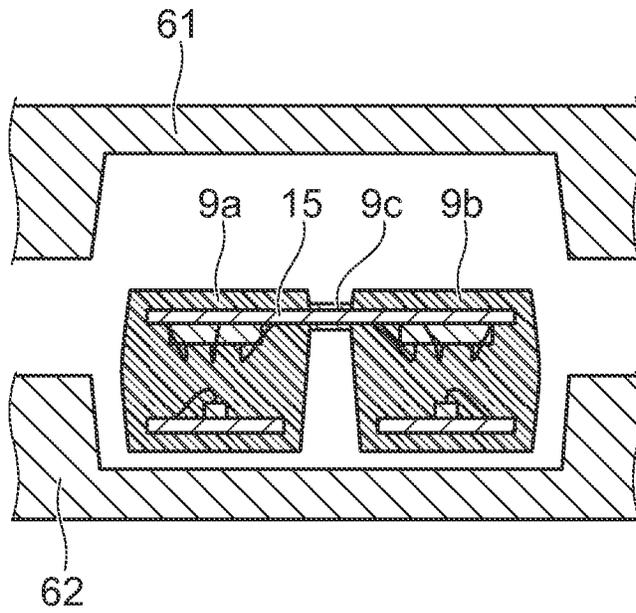


FIG. 7A

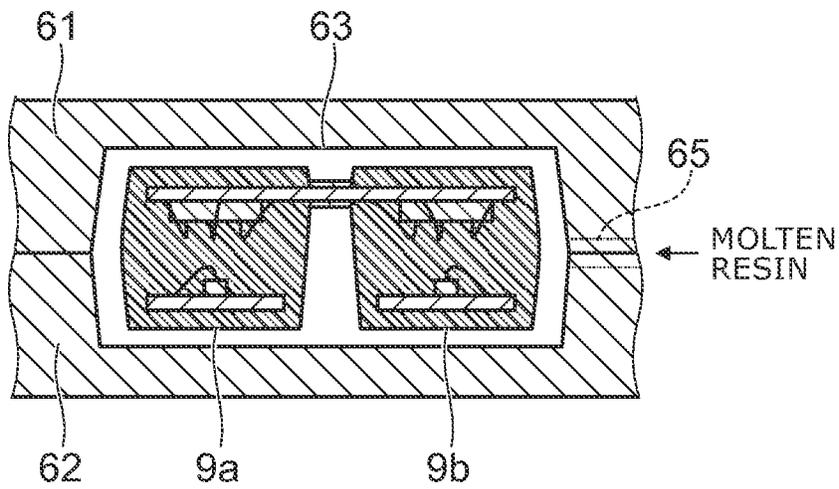


FIG. 7B

## SEMICONDUCTOR DEVICE AND METHOD FOR MANUFACTURING THE SAME

### CROSS-REFERENCE TO RELATED APPLICATIONS

This application is a continuation-in-part application of U.S. patent application Ser. No. 14/709,162, filed on May 11, 2015, which is a division of U.S. patent application Ser. No. 14/320,366, filed on Jun. 30, 2014, now U.S. Pat. No. 9,059,368, issued on Jun. 16, 2015, which is a division of U.S. patent application Ser. No. 13/425,232, filed Mar. 20, 2012, now abandoned, which is based upon and claims the benefit of priority from Japanese Patent Application No. 2011-224285, filed on Oct. 11, 2011; the entire contents of each of which are incorporated herein by reference.

### FIELD

Embodiments described herein relate generally to a semiconductor device and a method for manufacturing the same.

### BACKGROUND

A photocoupler, for example, which is a semiconductor device, includes a light emitting element and a light receiving element built-in and transmits a signal by an optical coupling. Therefore, the photocoupler is used for an isolation circuit that electrically insulates the primary side and the secondary side. Although the photocoupler has various uses, high insulating properties between the light emitting element on the primary side and the light receiving element on the secondary side are required in common. In addition, in a dual type product that includes two sets of a light emitting element and a light receiving element and has two transmission channels, it is necessary to suppress a crosstalk between channels.

For example, in a product in which the light receiving element side is connected to one frame, fabrication becomes easier by employing a method in which two sets of a light emitting element and a light receiving element are encapped by a one-body resin, but the crosstalk between channels cannot be suppressed. There is also a method in which two sets of a light emitting element and a light receiving element are individually encapped and are molded by a light blocking resin. The crosstalk can be suppressed by this method. However, a gap may be formed at the interface between the encap and the mold resin, and the dielectric breakdown voltage may be decreased. Thus, a semiconductor device in which the crosstalk between channels can be suppressed and the dielectric breakdown voltage can be increased and a method for manufacturing the same are required.

### BRIEF DESCRIPTION OF THE DRAWINGS

FIGS. 1A and 1B are schematic views showing a semiconductor device according to an embodiment;

FIGS. 2A and 2B are schematic views showing the semiconductor device according to the embodiment;

FIGS. 3A and 3B are schematic views illustrating a path of a current leak of the semiconductor device according to the embodiment;

FIGS. 4A and 4B are schematic views showing a lead frame according to the embodiment;

FIGS. 5A and 5B are schematic views showing a manufacturing process of the semiconductor device according to the embodiment;

FIGS. 6A to 6C are schematic views subsequent to FIG. 5B; and

FIGS. 7A and 7B are schematic views subsequent to FIGS. 6A to 6C.

### DETAILED DESCRIPTION

According to one embodiment, a semiconductor device including: a first molded body, a second molded body, and a third molded body. The first molded body covers a first light emitting element, a part of a primary lead electrically connected to the first light emitting element, a first light receiving element configured to detect a light emitted from the first light emitting element, and a part of a secondary lead electrically connected to the first light receiving element with a first resin. The second molded body covers a second light emitting element, a part of a primary lead electrically connected to the second light emitting element, a second light receiving element configured to detect a light emitted from the second light emitting element, and a part of a secondary lead electrically connected to the second light receiving element with the first resin. The third molded body molds the first molded body and the second molded body as one body using a second resin. One of the primary lead and the secondary lead is disposed to extend over the first molded body and the second molded body, and a surface of a portion extending between the first molded body and the second molded body is covered with a thin film made of the first resin.

Various embodiments will be described hereinafter with reference to the accompanying drawings. Identical components in the drawings are marked with the same reference numerals, and a detailed description thereof is omitted as appropriate and different components are described.

FIGS. 1A and 1B are schematic views showing a semiconductor device **100** according to an embodiment. FIG. 1A is a perspective view showing an external appearance, and FIG. 1B is a cross-sectional view taken along line  $I_b-I_b$  shown in FIG. 1A.

The semiconductor device **100** is, for example, a photocoupler, and includes a light emitting element and a light receiving element built-in. As shown in FIG. 1A, the semiconductor device **100** includes a resin package **10** and a plurality of terminals (leads) extending from the resin package **10**.

As shown in FIG. 1B, a light emitting element **7** and a light receiving element **13** are fixed to leads **5** and **15**, respectively, disposed away from each other, and are enclosed in the resin package **10**. The light emitting element **7** fixed to the lead **5** and the light receiving element **13** fixed to the lead **15** are disposed opposed to each other. That is, the light emitting surface of the light emitting element **7** and the light receiving surface of the light receiving element **13** are disposed opposed to each other, and the light receiving element **13** detects the signal light that the light emitting element **7** emits.

The resin package **10** includes an internal mold **9** enclosing the light emitting element **7** and the light receiving element **13** and an external mold **3** covering the exterior of the internal mold **9**. The internal mold **9** is made of, for example, a transparent resin; and transmits the light that the light emitting element **7** emits and causes the light to be incident on the light receiving surface of the light receiving element **13**. On the other hand, the external mold **3** is made of a resin that blocks the external light; and suppresses a dark current of the light receiving element **13** and reduces the noise level.

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The transparent resin used for the internal mold **9** preferably transmits 100% of the light emitted from the light emitting element **7**, but may absorb part of it. For example, an epoxy resin may be used.

A resin having the same main component as the internal mold **9** is preferably used for the external mold **3**. Thereby, the adhesion between the internal mold **9** and the external mold **3** can be improved. In the resin forming the external mold **3**, members that absorb the external light are scattered. For example, what is called a black resin in which carbon is scattered in an epoxy resin may be used. Furthermore, what is called a white resin in which members that reflect the external light are scattered may be used. For example, an epoxy resin in which a fine powder of titanium oxide is scattered may be used. Here, the external light refers to the background light excluding the light that the light emitting element **7** emits, for example, refers to light in a wavelength range in which the light receiving element **13** has sensitivity.

FIG. 2A is an opened-up view of the semiconductor device **100** as viewed from the upper surface. FIG. 2B is a cross-sectional view taken along line II<sub>a</sub>-II<sub>b</sub> in FIG. 2A. The semiconductor device **100** according to the embodiment includes two sets of the light emitting element **7** and the light receiving element **13**, and transmits signals of two channels.

As shown in FIG. 2A, the lead **15** to which the light receiving element **13** is fixed includes a first mount portion **15a** and a second mount portion **15b** (hereinafter a mount portion **15a** and a mount portion **15b**). The lead **15** further includes a portion connected to the mount portion **15a** and extending to the outside of the resin package **10**. Furthermore, two leads **17a** and **17b** that output a signal detected by the light receiving element **13** are provided. In addition, a lead **19** that supplies an electric power to the light receiving element **13** is provided.

On the other hand, the light emitting element **7** is fixed to leads **5a** and **5b** (see FIG. 3A) disposed opposed to the mount portion **15a** and the mount portion **15b**, respectively. Furthermore, leads **6a** and **6b** electrically connected to the light emitting element **7** via a metal wire are provided.

Thus, in the semiconductor device **100**, the leads **5a**, **5b**, **6a**, and **6b** that supply a drive current to the light emitting element **7** are provided as leads on the primary side. On the other hand, the leads **15**, **17a**, **17b**, and **19** are provided on the secondary side where a signal is outputted from the light receiving element **13**.

As shown in FIG. 2B, a light receiving element **13a** that is a first light receiving element is fixed to the mount portion **15a** of the lead **15**, and a light receiving element **13b** that is a second light receiving element is fixed to the mount portion **15b**. On the other hand, a light emitting element **7a** that is a first light emitting element is fixed to a mount portion **5c** connected to the lead **5a**, and a light emitting element **7b** that is a second light emitting element is fixed to a mount portion **5d** connected to the lead **5b**. The light emitting surface of the light emitting element **7a** and the light receiving surface of the light receiving element **13a** are disposed opposed to each other, and the light emitting surface of the light emitting element **7b** and the light receiving surface of the light receiving element **13b** are disposed opposed to each other.

The light receiving element **13a** fixed to the mount portion **15a** and the light emitting element **7a** fixed to the lead **5a** are enclosed in an internal mold **9a** that is a first molded body using a first resin. The light receiving element **13b** fixed to the mount portion **15b** and the light emitting element **7b** fixed to the lead **5b** are enclosed in an internal

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mold **9b** that is a second molded body using the first resin. The first resin is the transparent resin described above.

The internal molds **9a** and **9b** are covered with the external mold **3** that is a third molded body. The external mold **3** is molded by a second resin having light blocking properties. A shield portion **3a** is provided between the internal mold **9a** and the internal mold **9b**. The shield portion **3a** blocks the light of the light emitting element **7a** propagated toward the light receiving element **13b**, and blocks the light of the light emitting element **7b** propagated toward the light receiving element **13a**. Thereby, the crosstalk between channels is suppressed.

A connection portion **15c** that is part of the lead **15** and connects the mount portion **15b** and the mount portion **15a** is covered with a thin film **9c** made of the same first resin as that of the internal molds **9a** and **9b**. In the embodiment, the internal molds **9a** and **9b** are made of the same resin connected via the thin film **9c**, and are in a state of enclosing the lead **15** therein. Also the leads **5a** and **5b** to which the light emitting elements **7a** and **7b**, respectively, are fixed are enclosed in the same resin.

Furthermore, as shown in FIG. 2A, also the lead **19** that supplies an electric power to the light receiving elements **13a** and **13b** is provided to extend over the internal molds **9a** and **9b**. The lead **19** includes a portion enclosed in the internal mold **9a**, a portion enclosed in the internal mold **9b**, and a connection portion **19a** connecting them. Also the connection portion **19a** is covered with the thin film **9c**. That is, on the connection portion of the lead enclosed to extend over the internal molds **9a** and **9b**, the thin film **9c** covering the surface of the connection portion is provided.

Thereby, the dielectric breakdown voltage between the leads **5a**, **5b**, **6a**, and **6b** provided on the primary side and the leads **15**, **17a**, **17b**, and **19** provided on the secondary side can be increased.

FIGS. 3A and 3B are schematic views illustrating a path of a current leak between the leads **5a** and **6a** and the lead **15**. For example, if it is assumed that the dielectric breakdown voltage of the resin forming the internal molds **9a** and **9b** and the external mold **3** is sufficiently high, a path of a current leak will be formed at the interface between the internal mold **9a** or **9b** and the external mold **3**. That is, the adhesion between the internal molds **9a** and **9b** and the external mold **3** may be reduced, and water that has entered from the outside may reduce the insulating properties.

As shown in FIG. 3A, for example, a path **A<sub>1</sub>** along the interface between the internal mold **9a** and the external mold **3** may be formed as a leak path between the lead **6a** and the lead **15**. Furthermore, as shown in FIG. 3B, a path **A<sub>2</sub>** between the lead **5a** and the lead **15** may be formed.

In contrast, in the case where, for example, the thin film **9c** covering the connection portion **15c** does not exist, the connection portion **15c** is in a state of extending from the internal mold **9a** to the external mold **3** across the interface and further being inserted from the external mold **3** into the internal mold **9b** across the interface. Hence, for example, as shown in FIG. 3A, a leak path **B** will be formed between the lead **5a** and the connection portion **15c** of the lead **15**.

The distance between the lead **5a** and the connection portion **15c** in the leak path **B**, what is called the creeping distance, is shorter than the creeping distance of the path **A<sub>1</sub>** or **A<sub>2</sub>**. Therefore, the insulation resistance of the path **B** is smaller than the insulation resistance of the path **A<sub>1</sub>** or **A<sub>2</sub>**. Consequently, in the case where the thin film **9c** covering the connection portion **15c** of the lead **15** is not provided, the

dielectric breakdown voltage between the lead **6a** and the lead **5a** on the primary side and the lead **15** on the secondary side is decreased.

Thus, by covering the connection portions **15c** and **19a** of the leads provided to extend over the internal mold **9a** and the internal mold **9b** with the thin film **9c**, the path B with a short creeping distance can be eliminated, and the creeping distance between leads can be extended. Thereby, the dielectric breakdown voltage of the semiconductor device **100** can be increased.

Next, the manufacturing processes for the semiconductor device **100** are described with reference to FIG. **4A** to FIG. **7B**. FIGS. **4A** and **4B** are schematic views showing lead frames used in the manufacturing of the semiconductor device **100**. FIG. **5A** to FIG. **7B** are schematic views showing states of the lead frames in the processes.

FIG. **4A** shows a state where the light emitting elements **7a** and **7b** are fixed to a lead frame **20** that is a first frame. FIG. **4B** shows a state where the light receiving elements **13a** and **13b** are fixed to a lead frame **30** that is a second lead frame.

In the lead frame **20** shown in FIG. **4A**, a first to a fourth lead extending from a common frame **31** are provided. The ends of the first to fourth leads are provided away from one another. At the end of the lead **5a** that is the first lead, the mount portion **5c** is provided and the light emitting element **7a** is fixed. The lead **6a** that is the second lead is electrically connected to the light emitting element **7a** via a first wire **21a**. On the other hand, at the end of the lead **5b** that is the third lead, the mount portion **5d** is provided and the light emitting element **7b** is fixed. The lead **6b** that is the fourth lead is electrically connected to the light emitting element **7b** via a second wire **21b**.

The light emitting elements **7a** and **7b** are, for example, fixed to the mount portions **5c** and **5d**, respectively, via a conductive silver (Ag) paste. The wires **21a** and **21b** are, for example, gold (Au) wires, and are bonded between the electrodes of the light emitting elements **7a** and **7b** and the ends **6c** and **6d** of the leads **6a** and **6b**, respectively.

In the lead frame **30** shown in FIG. **4B**, four leads extending from a common frame **33** are provided. The four leads include a fifth to a seventh lead, and the ends of them are provided away from one another.

The mount portions **15a** and **15b** are provided at the end of the lead **15** that is the fifth lead. The light receiving element **13a** is fixed to the mount portion **15a**, and the light receiving element **13b** is fixed to the mount portion **15b**. The light receiving elements **13a** and **13b** may be fixed via, for example, an adhesive resin or an Ag paste. In the case where the light receiving elements **13a** and **13b** are silicon devices, they may be fixed via a silicide layer between the surface of the lead **15** and the back surfaces of the light receiving elements **13a** and **13b**.

The light receiving elements **13a** and **13b** each include a light receiving surface **13c**, a power supply terminal **13e**, a signal terminal **13f**, and a ground terminal **13g**. The power supply terminal **13e** is connected to the lead **19** via wires **23a** and **23b**. The signal terminal **13f** of the light receiving element **13a** is connected to the lead **17a** that is the sixth lead via a third wire **22a**. The signal terminal **13f** of the light receiving element **13b** is connected to the lead **17b** that is the seventh lead via a fourth wire **22b**. Furthermore, the ground terminal **13g** is connected to the lead **15** via wires **24a** and **24b**. The wires **22** to **24** are, for example, Au wires.

Next, the internal molds **9a** and **9b** are formed by the molding processes shown in FIGS. **5A** and **5B**. FIG. **5A** is a cross-sectional view showing a state where the lead frame

**20** and the lead frame **30** are set to be stacked between an upper die **41** and a lower die **42**. FIG. **5B** is a cross-sectional view showing a state where the upper die **41** and the lower die **42** are mold-clamped together.

As shown in FIG. **5A**, the lead frame **20** and the lead frame **30** are stacked, and are set on the lower die **42**. At this time, the light emitting surface **7c** of the light emitting element **7a** and the light receiving surface **13c** of the light receiving element **13a** are disposed opposed to each other, and the light emitting surface **7c** of the light emitting element **7b** and the light receiving surface **13c** of the light receiving element **13b** are disposed opposed to each other.

Subsequently, the upper die **41** and the lower die **42** are mold-clamped together to form a first cavity **43** and a second cavity **45**. The cavity **43** houses a portion of the lead **5a** to which the light emitting element **7a** is fixed, a portion of the lead **6a** to which the wire **21a** is bonded, the wire **21a**, the mount portion **15a** to which the light receiving element **13a** is fixed, a portion of the lead **17a** to which the wire **22a** is bonded, the wire **22a**, a portion of the lead **19** to which the wire **23a** is bonded, the wire **23a**, a portion to which the wire **24a** of the mount portion **15a** is bonded, and the wire **24a**.

The cavity **45** houses a portion of the lead **5b** to which the light emitting element **7b** is fixed, a portion of the lead **6b** to which the wire **21b** is bonded, the wire **21b**, the mount portion **15b** to which the light receiving element **13b** is fixed, a portion of the lead **17b** to which the wire **22b** is bonded, the wire **22b**, a portion of the lead **19** to which the wire **23b** is bonded, the wire **23b**, a portion to which the wire **24b** of the mount portion **15b** is bonded, and the wire **24b**.

Furthermore, the connection portion **15c** that is part of the lead **15** between the mount portion **15a** and the mount portion **15b** is housed in a gap **47** running from the cavity **43** to the cavity **45**.

Next, the first resin molten is injected into the cavity **45** via a runner **49a** communicating with the cavity **45**. Furthermore, in the embodiment, a through gate **49b** running from the cavity **45** to the cavity **43** is provided. Thereby, the first resin injected into the cavity **45** moves to the cavity **43**, and is put in both of the cavities **43** and **45**. The first resin is put also in the gap **47** that houses the connection portion **15c**.

At this time, it is also possible to move the molten resin from the cavity **45** to the cavity **43** via the gap **47**. However, in the case where the spacing of the gap **47** is made narrow and a thin-film-like resin is molded around the connection portion **15c** in order to suppress the crosstalk between channels, the resin may not smoothly move from the cavity **45** to the cavity **43**. Therefore, it is preferable to separately provide the through gate **49b** for injecting the resin from the cavity **45** to the cavity **43**. Furthermore, the runner **49a** for injecting the molten resin into the cavity **45** and the through gate **49b** are preferably provided at the same height from the bottom surfaces of the cavities **43** and **45**. The runner **49a** and the through gate **49b** are preferably provided so as to be aligned in a straight line in the injection direction of the molten resin.

Subsequently, the resin put in the cavities **43** and **45** is cured to mold the internal molds **9a** and **9b**. The internal mold **9a** is molded in the cavity **43**, and the internal mold **9b** is molded in the cavity **45**. The thin film **9c** is formed on the surface of the connection portion **15c**.

In the molding processes mentioned above, the connection portion **15c** between the mount portion **15a** and the mount portion **15b** and the connection portion **19a** of the lead **19** are housed in the gap **47**, and are therefore not caught and pressed between the upper die **41** and the lower

die 42. Thereby, the deformation of the lead 15 is suppressed, and the light receiving elements 13a and 13b can be molded in the respective prescribed positions in the internal molds 9a and 9b.

The embodiment illustrates an example in which the internal molds 9a and 9b are molded using dies of what is called a through gate type whereby the molten resin moves from the cavity 43 to the cavity 45 via the through gate 49b. The system of injection molding is not limited thereto, and the arrangement of the runner and the gate may be altered in accordance with the system of the lead frame, for example.

FIGS. 6A to 6C are schematic views showing the internal mold 9a and the internal mold 9b molded. FIG. 6A is a plan view, FIG. 6B is a front view, and FIG. 6C is a cross-sectional view taken along line V<sub>c</sub>-V<sub>c</sub>.

As shown in FIG. 6A to FIG. 6C, the leads 5a, 6a, 15, and 17a extend from the internal mold 9a, and the leads 5b, 6b, 17b, and 19 extend from the internal mold 9b. The connection portion 15c and the connection portion 19a covered with the thin film 9c are interposed between the internal mold 9a and the internal mold 9b. Furthermore, a runner portion resin 49c and a through gate portion resin 49d put in the runner 49a and the through gate 49b, respectively, are formed.

Next, the first resin formed around and between the internal molds 9a and 9b is removed. For example, the runner portion resin 49c and the through gate portion resin 49d formed in the portions of the runner 49a and the through gate 49b, respectively, a burr formed during molding, etc. are removed by punching processing using a punching blade matched with the external shapes of the inner molds 9a and 9b. After the runner portion resin 49c and the through gate portion resin 49d are removed, some parts 49cf and 49df of the runner portion resin 49c and the through gate portion resin 49d may be left as shown in FIG. 2A. Thereby, between the internal mold 9a and the internal mold 9b, the thin film 9c covering the connection portions 15c and 19a can be left and the surplus resin can be removed. The presence of parts 49cf and 49df may promote adhesion the second resin discussed below.

Next, by the molding processes shown in FIGS. 7A and 7B, the external mold 3 that covers the internal mold 9a, the internal mold 9b, and the connection portions 15c and 19a covered with the thin film 9c is molded.

As shown in FIG. 7A, the lead frames 20 and 30 with the internal molds 9a and 9b formed thereon are set on a lower die 62. Subsequently, an upper die 61 and the lower die 62 are mold-clamped to form a cavity 63.

Next, the second resin molten is injected via a runner 65 communicating with the cavity 63. Then, the resin put in the cavity 63 is cured to mold the external mold 3 covering the internal molds 9a and 9b and the thin film 9c. Subsequently, the lead frames 20 and 30 with the external mold 3 molded therearound are taken out of the dies, and the common frames 31 and 33 are cut to produce individually separated semiconductor devices 100.

In the manufacturing processes mentioned above, a hard epoxy resin, for example, may be used as the first resin; thereby, the strength of the connection portions 15c and 19a covered with the thin film 9c can be increased. Thereby, the deformation of the lead frames 20 and 30 with the internal molds 9a and 9b molded thereon can be suppressed, and the quality and manufacturing yield of the semiconductor device 100 can be improved.

While certain embodiments have been described, these embodiments have been presented by way of example only, and are not intended to limit the scope of the inventions.

Indeed, the novel embodiments described herein may be embodied in a variety of other forms; furthermore, various omissions, substitutions and changes in the form of the embodiments described herein may be made without departing from the spirit of the inventions. The accompanying claims and their equivalents are intended to cover such forms or modifications as would fall within the scope and spirit of the invention.

What is claimed is:

1. A semiconductor device comprising:

a first molded body comprised of a first resin and covering a first light emitting element, a part of a first primary lead electrically connected to the first light emitting element, a first light receiving element, and a part of a secondary lead electrically connected to the first light receiving element;

a second molded body comprised of the first resin and covering a second light emitting element, a part of a second primary lead electrically connected to the second light emitting element, a second light receiving element, and a part of the secondary lead electrically connected to the second light receiving element; and

a third molded body having a light-shielding portion between the first molded body and the second molded body, the third molded body covering the first molded body and the second molded body, and the first molded body having a first lateral surface on the light-shielding portion,

wherein the secondary lead has a connecting portion between the first molded body and the second molded body, the connecting portion being covered by a portion of first resin between the first molded body and the second molded body, and

the first molded body has a protruding portion of first resin protruding from the first lateral surface into the light-shielding portion, the protruding portion spaced from the connecting portion along the first lateral surface.

2. The device according to claim 1, wherein

a light emitting surface of the first light emitting element faces a light receiving surface of the first light receiving element; and

a light emitting surface of the second light emitting element faces a light receiving surface of the second light receiving element.

3. The device according to claim 1, wherein

the third molded body is comprised of a second resin; and a main component of the first resin is same as a main component of the second resin.

4. The device according to claim 1, wherein

the third molded body is comprised of a second resin; and the portion of first resin covering the connecting portion of the secondary lead is covered with the second resin.

5. The device according to claim 1, wherein

the first resin transmits light emitted from the first light emitting element and the second light emitting element; and

the third molded body is comprised of a second resin that blocks light emitted from the first light emitting element and the second light emitting element.

6. The device according to claim 1, wherein

the light-shielding portion blocks light emitted from the second light emitting element and blocks light emitted from the first light emitting element.

7. The device according to claim 1, wherein the secondary lead includes a first mount portion and a second mount portion, and the connecting portion is between the first mount portion and the second mount portion;

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the first light receiving element is mounted on the first mount portion; and  
the second light receiving element is mounted on the second mount portion.

- 8.** The device according to claim **1**, further comprising: 5  
a plurality of secondary leads, wherein  
each of the first light receiving element and the second light receiving element includes a light receiving surface, a power supply terminal, and a signal terminal; and  
a first one of the plurality secondary leads is electrically 10  
connected to the power supply terminals of the first and second light receiving elements;  
a second one of the plurality of secondary leads is electrically connected to the signal terminal of the first 15  
light receiving element; and  
a third one of the plurality of secondary leads is electrically connected to the signal terminal of the second light receiving element.
- 9.** The device according to claim **8**, wherein the first one of the plurality of secondary leads has a first portion, a

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second portion, and another connecting portion between the first portion and the second portion;

the first portion is disposed in the first molded body;  
the second portion is disposed in the second molded body;  
and

the another connecting portion is covered with first resin.

**10.** The device according to claim **1**, wherein each of the first primary lead, the second primary lead, and the secondary lead includes a portion extending outwardly from the 10  
third molded body.

**11.** The device according to claim **10**, wherein  
the third molded body has a first side surface and a second side surface opposite to the first side surface;  
the first primary lead and the second primary lead extend from the first side surface; and  
the secondary lead extends from the second side surface.

**12.** The device according to claim **1**, wherein all portions of the connecting portion that are between the first and second molded bodies are covered with first resin.

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